PESD5V0U1BA; PESD5V0U1BB; PESD5V0U1BL

Ultra low capacitance bidirectional ESD protection diodes

Rev. 01 — 25 April 2007

Product data sheet

Product profile

1.1 General description

Ultra low capacitance bidirectional ElectroStatic Discharge (ESD) protection diodes in small Surface-Mounted Device (SMD) plastic packages designed to protect one data line from the damage caused by ESD.

Table 1. **Product overview**

Type number	Package	Package	
	NXP	XP JEITA configuration	
PESD5V0U1BA	SOD323	SC-76	very small
PESD5V0U1BB	SOD523	SC-79	flat lead ultra small
PESD5V0U1BL	SOD882	-	leadless ultra small

1.2 Features

- Bidirectional ESD protection of one line Ultra low leakage current: I_{RM} = 5 nA
- Ultra low diode capacitance: C_d = 2.9 pF ESD protection of up to 10 kV
- IEC 61000-4-2; level 4 (ESD)

1.3 Applications

- Computers and peripherals
- Audio and video equipment
- Cellular handsets and accessories
- 10/100/1000 Ethernet
- Local Area Network (LAN) equipment
- Communication systems
- Portable electronics
- Subscriber Identity Module (SIM) card protection
- FireWire
- High-speed data lines

1.4 Quick reference data

Quick reference data

 $T_{amb} = 25 \,^{\circ}C$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Τνp	Max	Unit
				. , ,	111421	· · · · · ·
Per diode						
V_{RWM}	reverse standoff voltage		-	-	5	V
C_d	diode capacitance	$f = 1 MHz; V_R = 0 V$	-	2.9	3.5	pF



2. Pinning information

Table 3. Pinning

Pin	Description	Simplified outline	Symbol
SOD323; S	SOD523		
1	cathode 1	[1]	
2	cathode 2	001aab540	1 2 sym045
SOD882			
1	cathode 1	[1]	
2	cathode 2	Transparent top view	1 2 sym045

^[1] The marking bar indicates the cathode.

3. Ordering information

Table 4. Ordering information

Type number	Package		
	Name	Description	Version
PESD5V0U1BA	SC-76	plastic surface-mounted package; 2 leads	SOD323
PESD5V0U1BB	SC-79	plastic surface-mounted package; 2 leads	SOD523
PESD5V0U1BL	-	leadless ultra small plastic package; 2 terminals; body $1.0 \times 0.6 \times 0.5$ mm	SOD882

4. Marking

Table 5. Marking codes

Type number	Marking code
PESD5V0U1BA	AA
PESD5V0U1BB	B3
PESD5V0U1BL	AN

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per device					
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

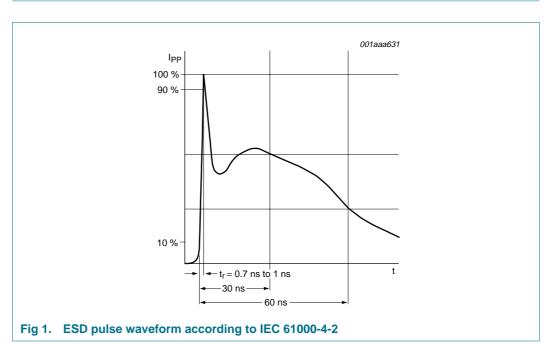
Table 7. ESD maximum ratings

Symbol	Parameter	Conditions		Min	Max	Unit
Per diode						
V _{ESD} electrostatic discharge voltage	IEC 61000-4-2 (contact discharge)	[1][2]	-	10	kV	
		MIL-STD-883 (human body model)		-	8	kV

^[1] Device stressed with ten non-repetitive ESD pulses.

Table 8. ESD standards compliance

Standard	Conditions
Per diode	
IEC 61000-4-2; level 4 (ESD)	> 15 kV (air); > 8 kV (contact)
MIL-STD-883; class 3 (human body model)	> 4 kV



^[2] Measured from pin 1 to pin 2.

6. Characteristics

Table 9. Characteristics

T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						
V_{RWM}	reverse standoff voltage		-	-	5	V
I_{RM}	reverse leakage current	$V_{RWM} = 5 V$	-	5	100	nA
V_{BR}	breakdown voltage	$I_R = 5 \text{ mA}$	5.5	7	9.5	V
C_d	diode capacitance	f = 1 MHz				
		$V_R = 0 V$	-	2.9	3.5	pF
		$V_R = 5 V$	-	1.9	-	pF
r _{dif}	differential resistance	$I_R = 1 \text{ mA}$	-	-	100	Ω

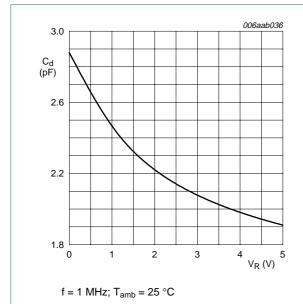


Fig 2. Diode capacitance as a function of reverse voltage; typical values

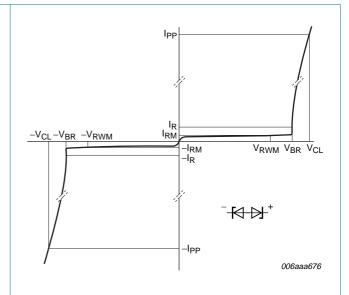
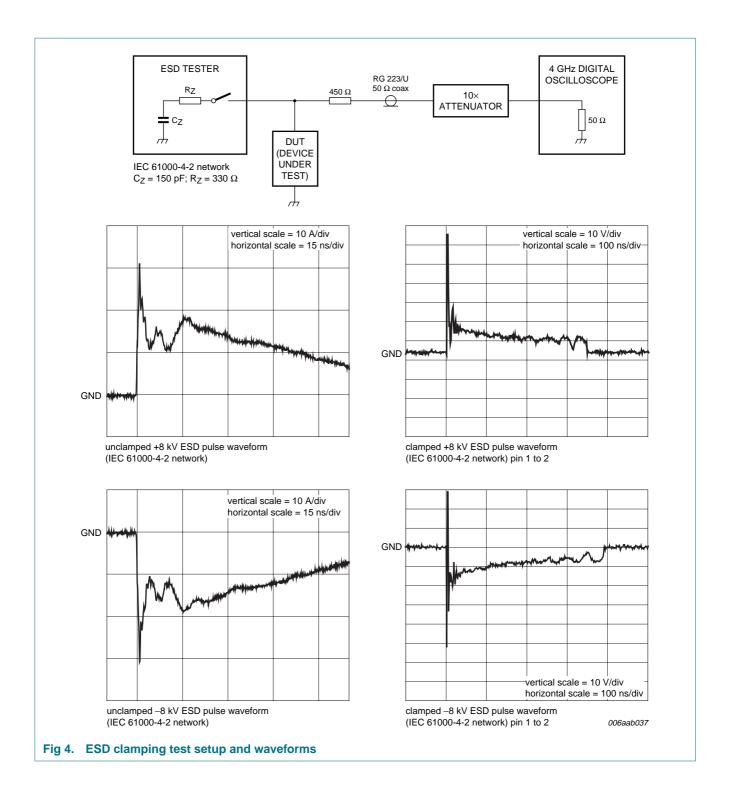


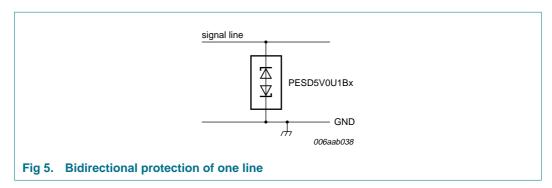
Fig 3. V-I characteristics for a bidirectional ESD protection diode

Ultra low capacitance bidirectional ESD protection diodes



7. Application information

The PESD5V0U1Bx series is designed for the bidirectional protection of one signal line from the damage caused by ESD pulses. The PESD5V0U1Bx series may be used on lines where the signal polarities are either positive or negative with respect to ground.

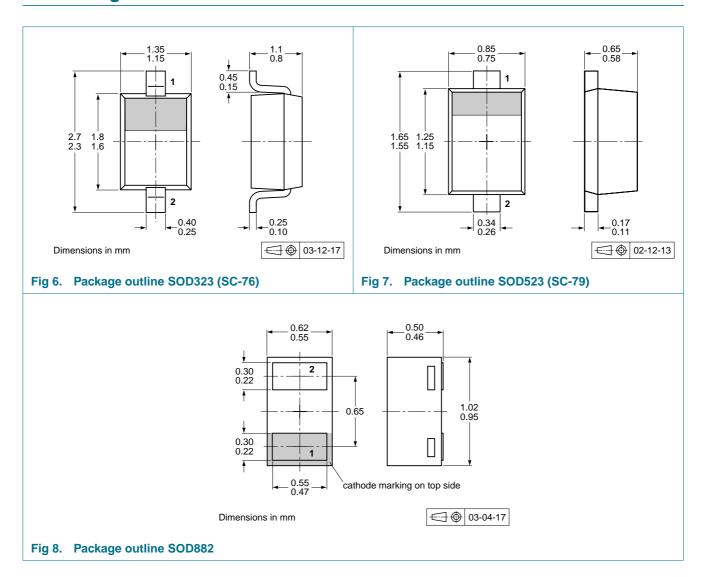


Circuit board layout and protection device placement

Circuit board layout is critical for the suppression of ESD, Electrical Fast Transient (EFT) and surge transients. The following guidelines are recommended:

- 1. Place the PESD5V0U1Bx as close to the input terminal or connector as possible.
- 2. The path length between the PESD5V0U1Bx and the protected line should be minimized.
- 3. Keep parallel signal paths to a minimum.
- 4. Avoid running protected conductors in parallel with unprotected conductors.
- 5. Minimize all Printed-Circuit Board (PCB) conductive loops including power and ground loops.
- 6. Minimize the length of the transient return path to ground.
- 7. Avoid using shared transient return paths to a common ground point.
- 8. Ground planes should be used whenever possible. For multilayer PCBs, use ground vias.

8. Package outline



9. Packing information

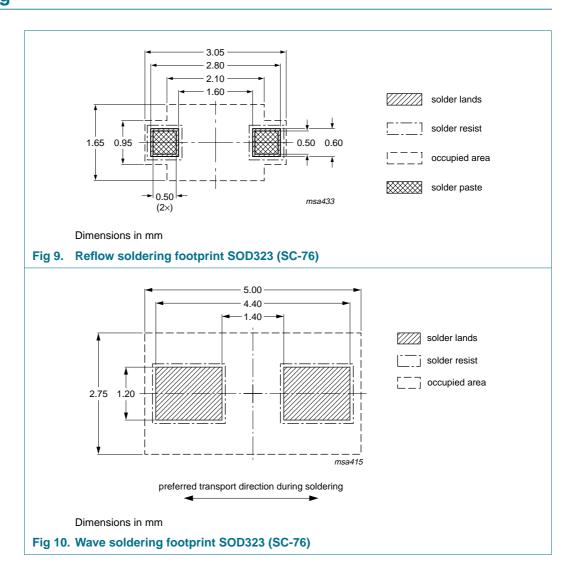
Table 10. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

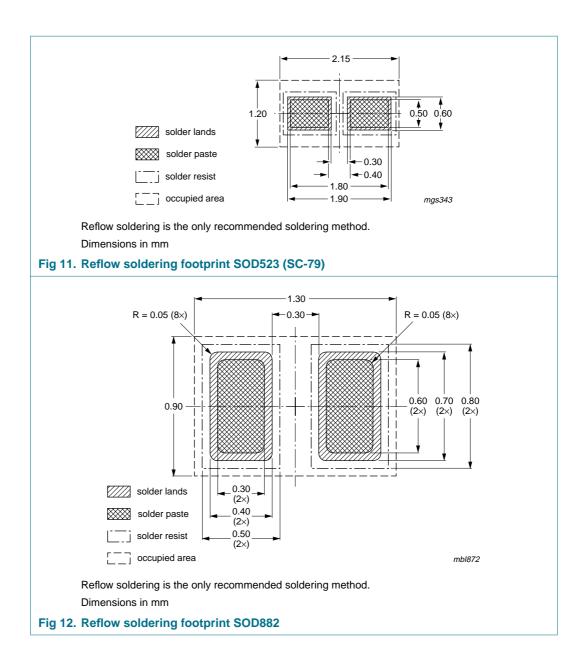
Type number	Package	Package Description		g quanti	ty
			3000	8000	10000
PESD5V0U1BA	SOD323	4 mm pitch, 8 mm tape and reel	-115	-	-135
PESD5V0U1BB	SOD523	2 mm pitch, 8 mm tape and reel	-	-315	-
		4 mm pitch, 8 mm tape and reel	-115	-	-135
PESD5V0U1BL	SOD882	2 mm pitch, 8 mm tape and reel	-	-	-315

^[1] For further information and the availability of packing methods, see Section 13.

10. Soldering



Ultra low capacitance bidirectional ESD protection diodes



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11. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PESD5V0U1BA_BB_BL_1	20070425	Product data sheet	-	-

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12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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